

Spezifikationen	
Teilenummer	DMP6180SK3-13
Hersteller	Diodes Incorporated
Beschreibung	MOSFET P-CH 60V 14A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	11236 pcs Stock
VGS (th) (Max) @ Id	2.7V @ 250µA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	TO-252
Serie	-
Rds On (Max) @ Id, Vgs	110 mOhm @ 12A, 10V
Verlustleistung (max)	1.7W (Ta)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	984.7pF @ 30V
Gate Charge (Qg) (Max) @ Vgs	17.1nC @ 10V
Typ FET	P-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	14A (Tc)

sein:

DMP6180SK3Q-13
Diodes Incorporated
MOSFET P-CHANNEL 60V 14A
TO252

DIODES
SEMICONDUCTORS

PERICOM POWER
MANAGED POWER TECHNOLOGIES

DMP6180SK3
DIODES
DMP6180SK3 DIODES

DMP6110SVT-7 MOS
DIODES
DIODES SOT-163

DIODES
SEMICONDUCTORS

PERICOM
SEMICONDUCTORS
ADVANCED POWER MANAGEMENT

DMP6110SVTQ
DIODES
DMP6110SVTQ DIODES

DMP6185SE-13
Diodes Incorporated
MOSFET PCH 60V 3A SOT223

DMP6110SVTQ-7
Diodes Incorporated
MOSFET BVDSS: 41V 60V
TSOT26

DMP6110SVTQ-13
Diodes Incorporated
MOSFET BVDSS: 41V 60V
TSOT26

DMP6180SK3-13 MOS
DIODES
DIODES TO-252

Mehr

Diodes Incorporated	DMP6180SK3-13 Datenblatt	DMP6180SK3-13-Datenblätter	DMP6180SK3-13 PDF	Diodes Incorporated DMP6180SK3-13
DMP6180SK3-13 Electronic	DMP6180SK3-13-Komponenten	DMP6180SK3-13-Verteiler	DMP6180SK3-13-Bild	DMP6180SK3-13-Teil
DMP6180SK3-13 Preis	DMP6180SK3-13 Hersteller	DMP6180SK3-13 Bild	DMP6180SK3-13 Aktie	DMP6180SK3-13 Inventar
DMP6180SK3-13 Neu	DMP6180SK3-13 Original	DMP6180SK3-13 garantiert	DMP6180SK3-13 RFQ	DMP6180SK3-13 Online bestellen